## The Synergistic Effect of Topography and Stiffness as a Crack

## Engineering Strategy for Stretchable Electronics

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**Figure S1.** AFM characterization of PDMS/PVAc<sub>planar</sub>. (a) AFM image of the PDMS/PVAc<sub>planar</sub> surface, (b) AFM image of a PVAc film step on glass with the corresponding plot of the film thickness.



**Figure S2.** Optical microscope images and the corresponding image analysis showing topographical coverage in PDMS/PVAc, glass/PVAc, and PDMS-RM/PVAc when the samples are prepared from PVAc dilutions of (a) 1:1, (b) 3:1, and (c) 5:1 water:glue (v:v). Scale bars are 50 μm.



Figure S3. Plots of change in resistance with elongation of PDMS/PVAc/Au (red squares) and PDMS-RM/Au (blue circles) systems with (a) 100%, (b) 82%, and (c) 48% topographical coverage. Data points in the plots represent average  $R/R_0 \pm$  standard deviation of at least 3 samples.



**Figure S4.** Plots and fits of (R-R<sub>0</sub>)/R<sub>0</sub> with increasing mechanical strain of (**a**) PDMS/PVAc<sub>planar</sub>/Au, (**b**) PDMS-RM<sub>100</sub>/Au (**c**) PDMS-RM<sub>82</sub>/Au, (**d**) PDMS-RM<sub>48</sub>/Au, and (**e**) PDMS/PVAc/Au with 100% PVAc coverage (blue circles), 82% PVAc coverage (red squares),

and 48% PVAc coverage (green triangles). Data points in the plots represent average  $R/R_0 \pm$  standard deviation of at least 3 samples.

Sensor Material	Gauge Factor	Linear Working	Reference
		Range	
PDMS/PVAc <sub>48</sub> /Au	114	0-95 %	This work
PDMS/PVAc <sub>82</sub> /Au	72	0-100 %	This work
PDMS/PVAc <sub>100</sub> /Au	27	0-95 %	This work
Au film on nitrile	62	0 - 40 %	Mechael, S., et al. <sup>1</sup>
butadiene rubber			
AuNPs on PDMS	2.05	0 - 20 %	Lee, J., <i>et al.</i> <sup>2</sup>
Au film on PET	1600	0-2%	Lee, T., et al. <sup>3</sup>
AgNWs on latex	6.9	0-50 %	Gong, S., et al. <sup>4</sup>
AgNWs on PDMS	5	0-60%	Amjadi, M., et al. <sup>5</sup>
AgNWs on PDMS	24.6	0-130 %	Kim, K-H, et al. <sup>6</sup>
ZnO NWs on polystyrene	116	0-50 %	Xiao, X., et al. <sup>7</sup>
CNT fibers on Ecoflex	0.56	0 - 200 %	Ryu, S., <i>et al.</i> <sup>8</sup>
CNTs on ecoflex	1.75	0-100 %	Amjadi, M., et al.9
CNTs on PDMS	0.82	0 - 40 %	Yamada, T., et al. <sup>10</sup>
Graphene nanoribbons	7.9	0-60%	Tan, C., <i>et al.</i> <sup>11</sup>
on polyurethane			
Graphene nanocellulose	7.1	0-100 %	Yan, C., <i>et al</i> . <sup>12</sup>
paper			
Graphene foam	15	0-77 %	Jeong, Y. R., et
			al. <sup>13</sup>
Graphene foam PDMS	98.66	0-5%	Li, J., <i>et al</i> . <sup>14</sup>
Reduced graphene oxide	754	0-5%	Ye, X., <i>et al</i> . <sup>15</sup>
(rGO) polyethylenimine			
layered nanocomposite			
rGO-PDMS composite	7.2	0-110 %	Zheng, Z., et al. <sup>16</sup>
Graphene/carbon	138	0-16 %	Sun, S., <i>et al</i> . <sup>17</sup>
black/Ni sponge			
Carbon black and PDMS	5.5	0-10 %	Kong, J-H., <i>et al.</i> <sup>18</sup>

Table S1. Gauge factors and working ranges of reported strain sensing systems

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